## Cheng-Wei Cheng

## List of Publications by Year in descending order

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Version: 2024-02-01


The effect of interface processing on the distribution of interfacial defect states and the C-V
4 characteristics of $I I I-V$ metal-oxide-semiconductor field effect transistors. Journal of Applied Physics,
2.5 2011, 109, 023714.
(Invited) Effect of A <sub> $2</$ sub> O <sub> $3</$ sub>/InGaAs Interface on Channel Mobility. ECS Transactions, 2011, 41, 219-225.
$0.5 \quad 2$

Improved interfacial state density in $\mathrm{Al} 2 \mathrm{O} 3 / \mathrm{GaAs}$ interfaces using metal-organic chemical vapor deposition. Applied Physics Letters, 2010, 96, .

